

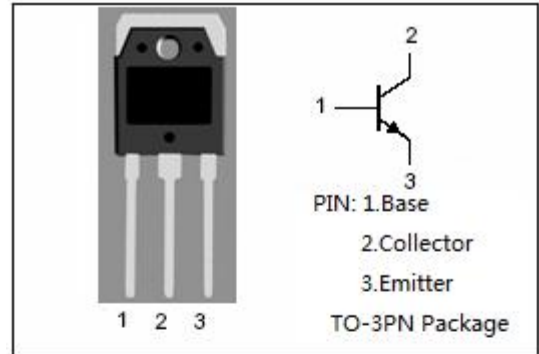
## Silicon NPN Power Transistor

### DESCRIPTION

- High Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 400V(\text{Min})$
- High Switching Speed
- High Reliability

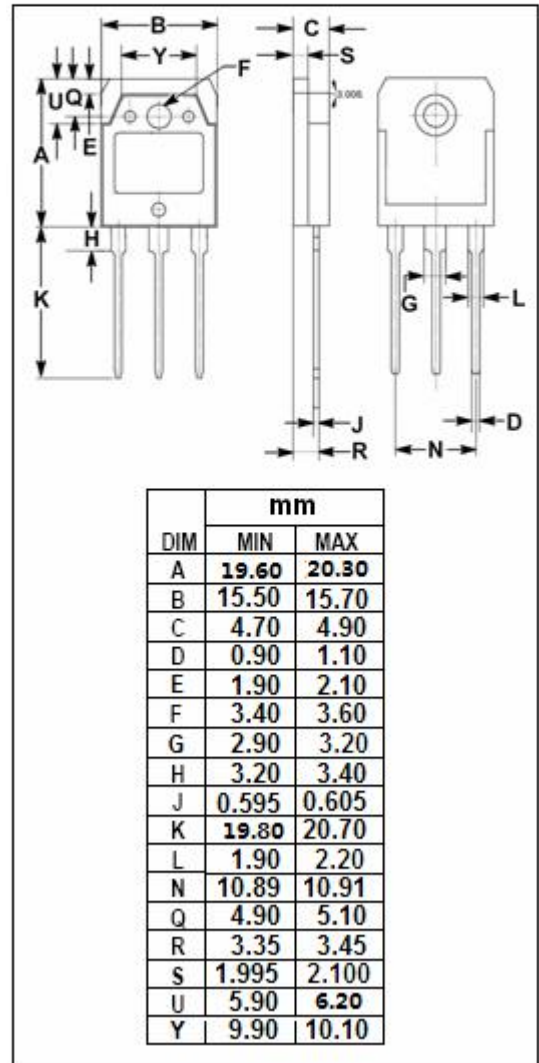
### APPLICATIONS

- Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers



### ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	500	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
$V_{CEO(SUS)}$	Collector-Emitter Voltage	400	V
$V_{EBO}$	Emitter-Base Voltage	7	V
$I_C$	Collector Current-Continuous	15	A
$I_B$	Base Current-Continuous	5	A
$P_C$	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	80	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-65~150	$^\circ\text{C}$



### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	1.56	$^\circ\text{C}/\text{W}$

### Ordering Information

Product	Package	Packaging
2LSC3320T4TL	TO-3PN	Tube



## ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C=10\text{mA}; I_B=0$	400			V
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C=50\text{mA}; I_B=0$	400			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C=1\text{mA}; I_E=0$	500			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E=1\text{mA}; I_C=0$	7			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=6\text{A}; I_B=1.2\text{A}$			1.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=6\text{A}; I_B=1.2\text{A}$			1.5	V
$I_{CBO}$	Collector Cutoff Current	$V_{CB}=500\text{V}; I_E=0$			1.0	mA
$I_{EBO}$	Emitter Cutoff Current	$V_{EB}=7\text{V}; I_C=0$			1.0	mA
$h_{FE}$	DC Current Gain	$I_C=6\text{A}; V_{CE}=5\text{V}$	10			

### Switching times

$t_{on}$	Turn-on Time	$I_C=7.5\text{A}; I_{B1}=1.5\text{A}; I_{B2}=-3\text{A}$ $R_L=20\Omega; P_W=20\mu\text{s}$ Duty $\leq 2\%$			0.5	$\mu\text{s}$
$t_{stg}$	Storage Time				1.5	$\mu\text{s}$
$t_f$	Fall Time				0.15	$\mu\text{s}$